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Texas Instruments
TRF370333IRGET

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Datasheet of TRF370333IRGET - IC QUADRATURE MODULATOR 24-QFN

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TRF370315 TRF370333

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0.35-GHz TO 4-GHz QUADRATURE MODULATORS

Check for Samples: TRF370315, TRF370333

FEATURES

- 75-dBc Single-Carrier WCDMA ACPR at –11-dBm Channel Power
- Low Noise Floor: –163 dBm/Hz
- OIP3 of 23 dBm
- P1dB of 9 dBm
- Unadjusted Carrier Feedthrough of –40 dBm
- Unadjusted Side-Band Suppression of –40 dBc
- Single Supply: 4.5 V–5.5 V Operation
- Silicon Germanium Technology
- TRF370333 With 3.3-V CM at I, Q Baseband Inputs
- TRF370315 With 1.5-V CM at I, Q Baseband Inputs

APPLICATIONS

- Cellular Base Transceiver Station Transmit Channel
- CDMA: IS95, UMTS, CDMA2000, TD-SCDMA

RGE PACKAGE

- TDMA: GSM, IS-136, EDGE/UWC-136
- Wireless Local Loop
- Wireless MAN Wideband Transceivers

(TOP VIEW) GND GND GND BBI (18)VCC NC 1 **GND** (17 **GND** 2 3 (16)RF OUT LOP LON (15)NC 4 **GND** 5 (14 **GND** $(\overline{13}$ NC 6 NC GND GND

P0024-04

DESCRIPTION

The TRF370315 and TRF370333 are low-noise direct quadrature modulators, capable of converting complex modulated signals from baseband or IF directly up to RF. The TRF370315 and TRF370333 are ideal for high-performance direct RF modulation from 350 MHz up to 4 GHz. These modulators are implemented as a double-balanced mixer. The RF output block consists of a differential to single-ended converter and an RF amplifier capable of driving a single-ended $50-\Omega$ load without any need of external components. The TRF370333 and TRF370315 devices have different common-mode voltage ratings at the I/Q baseband inputs. The TRF370315 requires a 1.5-V common-mode voltage, and the TRF370333 requires a 3.3-V common-mode voltage.

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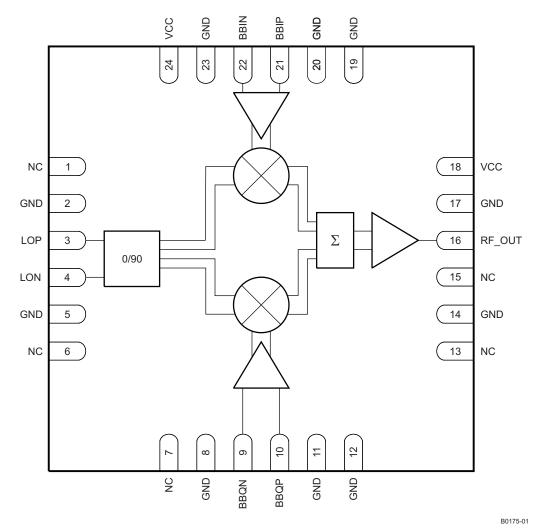
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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

FUNCTIONAL BLOCK DIAGRAM



NOTE: NC = No connection



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DEVICE INFORMATION

TERMINAL FUNCTIONS

TEI	RMINAL	1/0	DESCRIPTION
NAME	NO.	I/O	DESCRIPTION
BBIN	22	I	In-phase input
BBIP	21	I	In-phase input
BBQN	9	I	In-quadrature input
BBQP	10	I	In-quadrature input
GND	2, 5, 8,11, 12, 14, 17, 19, 20, 23	_	Ground
LON	4	I	Local oscillator input
LOP	3	I	Local oscillator input
NC	1, 6, 7, 13, 15	_	No connect
RF_OUT	16	0	RF output
VCC	18, 24	_	Power supply

ABSOLUTE MAXIMUM RATINGS(1)

Over operating free-air temperature range (unless otherwise noted).

			VALUE ⁽²⁾	UNIT
	Supply voltage range		-0.3 V to 6	V
	Digital I/O voltage range		-0.3 V to V _I + 0.3	V
T_J	Operating virtual junction temper	Operating virtual junction temperature range		°C
T _A	Operating ambient temperature	range	-40 to 85	°C
T _{stg}	Storage temperature range		–65 to 150	°C
CCD		Human body model (HBM)	75	V
ESD	ESD Electrostatic discharge ratings	Charged device model (CDM)	75	V

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

Over operating free-air temperature range (unless otherwise noted).

		MIN	NOM	MAX	UNIT
V_{CC}	Power-supply voltage	4.5	5	5.5	V

THERMAL CHARACTERISTICS

	PARAMETER	TEST CONDITIONS	VALUE	UNIT
$R_{\theta JA}$	Thermal resistance, junction-to-ambient	High-K board, still air	29.4	°C/W
$R_{\theta JC}$	Thermal resistance, junction-to-case		18.6	°C/W

⁽²⁾ All voltage values are with respect to network ground terminal.



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ELECTRICAL CHARACTERISTICS

Over operating free-air temperature range (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
DC Para	meters					
	Total supply current (1.5 V CM)	T _A = 25°C		195	205	A
I _{CC}	Total supply current (3.3 V CM)	T _A = 25°C		210	235	mA
LO Input	(50-Ω, Single-Ended)		·			
	LO frequency range		0.35		4	GHz
f_{LO}	LO input power		- 5	0	12	dBm
	LO port return loss			15		dB
Baseban	d Inputs		·			
	Land Circuit de comment units an	TRF370333		3.3		V
V_{CM}	I and Q input dc common voltage	TRF370315		1.5		V
BW	1-dB input frequency bandwidth		350			MHz
	Input impedance, resistance	TDF070000		10		kΩ
$Z_{I(single}$	Input impedance, parallel capacitance	TRF370333		3		pF
ended)	Input impedance, resistance	TDF270245		5		kΩ
	Input impedance, parallel capacitance	TRF370315		3		pF

ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V, $T_A = 25^{\circ}C$, $f_{LO} = 350$ MHz at 0 dBm, TRF370333 (unless otherwise noted).

RF Output Parameters								
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
G	Voltage gain ⁽¹⁾	TRF370315: Output RMS voltage over input I (or Q) RMS voltage		-4.18		dB		
		TRF370333: Output RMS voltage over input I (or Q) RMS voltage		-4.0		dB		
P1dB	Output compression point			9.4		dBm		
IP3	Output IP3			24.5		dBm		
IP2	Output IP2	Measured at f _{LO} + 2 × f _{BB}		73.8		dBm		
	Carrier feedthrough	Unadjusted		35.6		dBm		
	Sideband suppression	Unadjusted		33.8		dBc		
		DC only to BB inputs, 13 MHz offset from f _{LO}		-158.0				
	Output noise floor	1.8-MHz offset from f _{LO} ; 1 CW tone; P _{out} = 0 dBm		-152.6		dBm/Hz		
		6-MHz offset from f _{LO} ; 1 CW tone; P _{out} = 0 dBm		-157.4				

⁽¹⁾ Single 4-MHz CW baseband input tone, differential-ended 196 V_{RMS} .

ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V, $T_A = 25^{\circ}C$, $f_{LO} = 400$ MHz at 0 dBm, TRF370315 (unless otherwise noted).

RF Outp	ut Parameters					
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
G	Valtage rain (1)	TRF370315: Output RMS voltage over input I (or Q) RMS voltage		-2.409		dB
	Voltage gain ⁽¹⁾	TRF370333: Output RMS voltage over input I (or Q) RMS voltage		-1.905		dB
P1dB	Output compression point			9.4		dBm
IP3	Output IP3		20	23		dBm
IP2	Output IP2	Measured at f _{LO} + 2 × f _{BB}		62		dBm
	Carrier feedthrough	Unadjusted		-37		dBm
	Sideband suppression	Unadjusted		-39		dBc

⁽¹⁾ Single 4-MHz CW baseband input tone, differential-ended 196 V_{RMS} .



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ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V, $T_A = 25$ °C, $f_{LO} = 900$ MHz at 0 dBm, TRF370315 (unless

RF Out	put Parameters					
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
G	Voltage gain ⁽¹⁾	TRF370315: Output RMS voltage over input I (or Q) RMS voltage		-3.552		dB
G	TRF370333: Output RMS voltage over input I (or Q) RMS voltage		-2.79		dB	
P1dB	Output compression point			9		dBm
IP3	Output IP3		20	23		dBm
IP2	Output IP2	Measured at f _{LO} + 2 × f _{BB}		63		dBm
	Carrier feedthrough	Unadjusted		-37		dBm
	Sideband suppression	Unadjusted		-42		dBc
	Output return loss			9		dB
		DC only to BB inputs, 13 MHz offset from f _{LO}		-160.4		
	Output noise floor	1.8-MHz offset from f _{LO} ; 1 CW tone; P _{out} = 0 dBm		-156.6		dBm/Hz
		6-MHz offset from f _{LO} ; 1 CW tone; P _{out} = 0 dBm		-158.5		
		1 EDGE signal, P _{out} = –5 dBm		0.59%		
EVM	Error vector magnitude (rms)	1 EDGE signal, P _{out} = 0 dBm		0.63%		
_ v IVI	Error vector magnitude (mis)	1 EDGE signal, P _{out} = 0 dBm, 2nd harmonic of LO = -15 dBm, 3rd harmonic of LO = -33 dBm ⁽²⁾		1%		

ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V, $T_A = 25$ °C, $f_{LO} = 1800$ MHz at 0 dBm, TRF370315 (unless otherwise noted).

RF Outp	out Parameters					
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
G	Voltage gain ⁽¹⁾	TRF370315: Output RMS voltage over input I (or Q) RMS voltage		-3.345		dB
9	voitage gain	TRF370333: Output RMS voltage over input I (or Q) RMS voltage		-2.367		dB
P1dB	Output compression point			9.5		dBm
IP3	Output IP3		20	23		dBm
IP2	Output IP2	Measured at f _{LO} + 2 × f _{BB}		55		dBm
	Carrier feedthrough	Unadjusted		-40		dBm
	Sideband suppression	Unadjusted		-47		dBc
	Output return loss			8		dB
		DC only to BB inputs, 13 MHz offset from f _{LO}		-162.6		
	Output noise floor	1.8-MHz offset from f _{LO} ; 1 CW tone; P _{out} = 0 dBm		-160		dBm/Hz
		6-MHz offset from f _{LO} ; 1 CW tone; P _{out} = 0 dBm		-159.4		
		1 EDGE signal, P _{out} = –5 dBm		0.66%		
EVM	Error vector magnitude (rms)	1 EDGE signal, P _{out} = 0 dBm		0.74%		
L V IVI	Error vector magnitude (rms)	1 EDGE signal, P _{out} = 0 dBm, 2nd harmonic of LO = -15.5 dBm, 3rd harmonic of LO = -30 dBm ⁽²⁾		1%		

Single 4-MHz CW baseband input tone, differential-ended 196 V_{RMS} . The second- and third-harmonic tests were made independently at each frequency.

Single 4-MHz CW baseband input tone, differential-ended 196 V_{RMS} . The second- and third-harmonic tests were made independently at each frequency.



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ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V, $T_A = 25$ °C, $f_{LO} = 1960$ MHz at 0 dBm, TRF370315 (unless otherwise noted).

RF Out	put Parameters					
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
G	Voltage gain ⁽¹⁾	TRF370315: Output RMS voltage over input I (or Q) RMS voltage		-3.449		dB
9	voltage gain v	TRF370333: Output RMS voltage over input I (or Q) RMS voltage		-2.479		dB
P1dB	Output compression point			9.5		dBm
IDO	Output IP3, TRF370315		20	23		dD.m
IP3	Output IP3, TRF370333		18	20		dBm
IP2	Output IP2	Measured at f _{LO} + 2 × f _{BB}		55		dBm
	Carrier feedthrough	Unadjusted		-40		dBm
	Sideband suppression	Unadjusted		-47		dBc
	Output return loss			8		dB
		DC only to BB inputs, 13 MHz offset from f _{LO}		-162.6		
	Output noise floor	1.8-MHz offset from f _{LO} ; 1 CW tone; P _{out} = 0 dBm		-160		dBm/Hz
		6-MHz offset from f _{LO} ; 1 CW tone; P _{out} = 0 dBm		-159.4		
		1 EDGE signal, P _{out} = -5 dBm		0.66%		
EVM	Error vector magnitude (rms)	1 EDGE signal, P _{out} = 0 dBm		0.74%		
_ v Ivi	Error vector magnitude (mis)	1 EDGE signal, P _{out} = 0 dBm, 2nd harmonic of LO = -15.5 dBm, 3rd harmonic of LO = -30 dBm ⁽²⁾		1%		

Single 4-MHz CW baseband input tone, differential-ended 196 V_{RMS} .

ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V, T_A = 25°C, f_{LO} = 2140 MHz at 0 dBm, TRF370315 (unless otherwise noted).

RF Outp	out Parameters					
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
0	V-14 (1)	TRF370315: Output RMS voltage over input I (or Q) RMS voltage		-3.432		dB
G	Voltage gain ⁽¹⁾	TRF370333: Output RMS voltage over input I (or Q) RMS voltage		-2.791		dB
P1dB	Output compression point			9.5		dBm
ID2	Output IP3, TRF370315		20	23		dD.m
IP3	Output IP3, TRF370333		18	21		dBm
IP2	Output IP2	Measured at f _{LO} + 2 × f _{BB}		58		dBm
	Carrier feedthrough	Unadjusted		-40		dBm
	Sideband suppression	Unadjusted		-47		dBc
	Output return loss			8.5		dB
		20-MHz offset from f _{LO} ; dc only to BB inputs		-163		
	Output noise floor	20-MHz offset from f _{LO} ; 1 WCDMA signal; P _{in} = -20.5 dBVrms (I and Q input)		-162		dBm/Hz
		1 WCDMA signal; P _{out} = –13 dBm		-75.8		
ACPR	Adjacent-channel power ratio	1 WCDMA signal; P _{out} = –9 dBm		-72		dBc
	Tatio	4 WCDMA signals; P _{out} = −23 dBm per carrier		-68		
		1 WCDMA signal; P _{out} = -13 dBm		– 79		
	Alternate-channel power ratio	1 WCDMA signal; P _{out} = –9 dBm		-80.5		dBc
	Tallo	4 WCDMA signals; P _{out} = -23 dBm per carrier		-69		

Single 4-MHz CW baseband input tone, differential-ended 196 V_{RMS} .

The second- and third-harmonic tests were made independently at each frequency.



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ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V, $T_A = 25$ °C, $f_{LO} = 2500$ MHz at 0 dBm, TRF370315 (unless otherwise noted).

RF Output Parameters								
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
C	Valtage gain (1)	TRF370315: Output RMS voltage over input I (or Q) RMS voltage		-2.892		dB		
G	Voltage gain ⁽¹⁾	TRF370333: Output RMS voltage over input I (or Q) RMS voltage		-1.379		dB		
P1dB	Output compression point			9.5		dBm		
IP3	Output IP3		18	21		dBm		
IP2	Output IP2	Measured at f _{LO} + 2 × f _{BB}		63		dBm		
	Carrier feedthrough	Unadjusted		-38		dBm		
	Sideband suppression	Unadjusted		-47		dBc		

⁽¹⁾ Single 4-MHz CW baseband input tone, differential-ended 196 V_{RMS} .

ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V, $T_A = 25$ °C, $f_{LO} = 3600$ MHz at 0 dBm, TRF370315 (unless otherwise noted).

RF Output Parameters										
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT				
0	Valta va vaiv (1)	TRF370315: Output RMS voltage over input I (or Q) RMS voltage		-1.265		dB				
G	Voltage gain ⁽¹⁾	TRF370333: Output RMS voltage over input I (or Q) RMS voltage		1.529		dB				
P1dB	Output compression point			9.5		dBm				
IP3	Output IP3		20	23		dBm				
IP2	Output IP2	Measured at f _{LO} + 2 × f _{BB}		63		dBm				
	Carrier feedthrough	Unadjusted		-41		dBm				
	Sideband suppression	Unadjusted		-45		dBc				

⁽¹⁾ Single 4-MHz CW baseband input tone, differential-ended 196 V_{RMS} .

ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, power supply = 5 V, $T_A = 25^{\circ}$ C, $f_{LO} = 4000$ MHz at 0 dBm, TRF370315 (unless otherwise noted).

RF Output Parameters										
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT				
0	Valtage main (1)	TRF370315: Output RMS voltage over input I (or Q) RMS voltage		-2.242		dB				
G	Voltage gain ⁽¹⁾	TRF370333: Output RMS voltage over input I (or Q) RMS voltage		0.543		dB				
P1dB	Output compression point			9		dBm				
IP3	Output IP3		19	22		dBm				
IP2	Output IP2	Measured at f _{LO} + 2 × f _{BB}		50		dBm				
	Carrier feedthrough	Unadjusted		-37		dBm				
	Sideband suppression	Unadjusted		-40		dBc				

⁽¹⁾ Single 4-MHz CW baseband input tone, differential-ended 196 V_{RMS} .

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TYPICAL CHARACTERISTICS

OUTPUT POWER BASEBAND VOLTAGE 15 TRF3703-15 TRF3703-33 10 P_{OUT} - Output Power at 1.8 GHz - dBm 5 0 -5 -10 -15 -20 0.01 0.1 VBB - Baseband Voltage, Single-Ended, RMS - V

Figure 1.

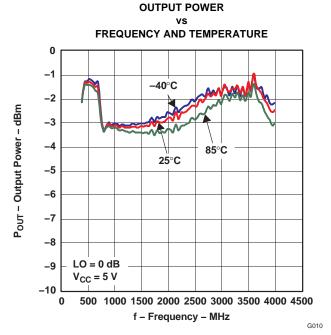


Figure 2.

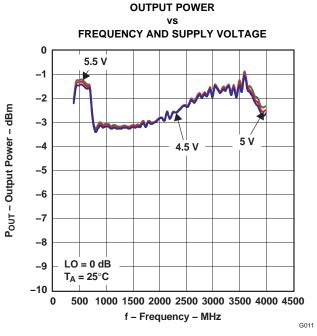


Figure 3.

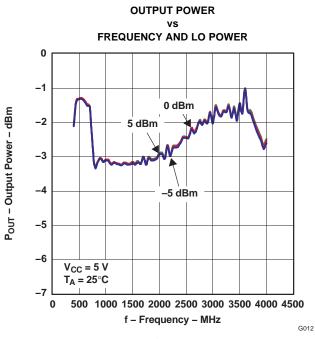


Figure 4.

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TEXAS

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TYPICAL CHARACTERISTICS (continued)

P1dB - dBm

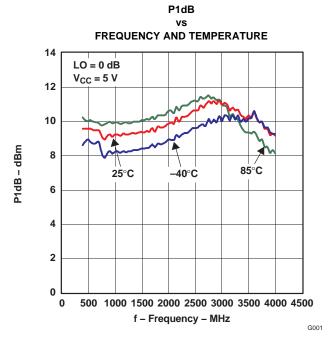
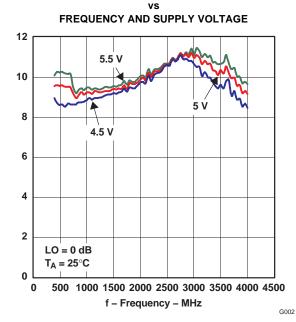


Figure 5.



P1dB

Figure 6.

TRF370315

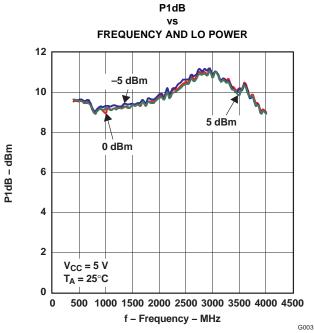


Figure 7.

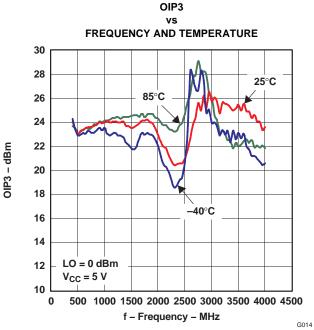


Figure 8.

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TYPICAL CHARACTERISTICS (continued)

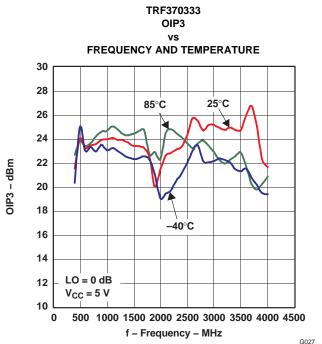


Figure 9.

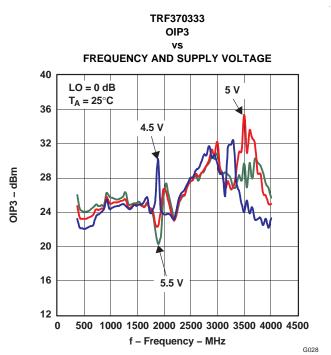
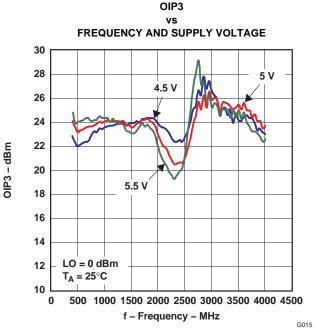


Figure 11.



TRF370315

Figure 10.

TRF370315

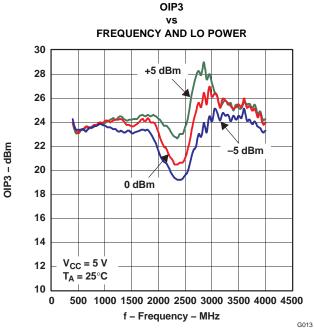


Figure 12.

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TYPICAL CHARACTERISTICS (continued)

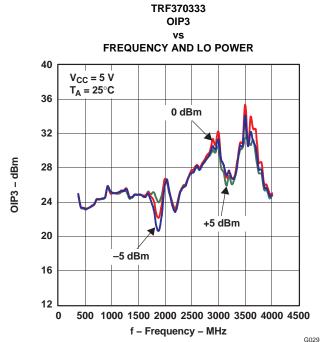


Figure 13.

FREQUENCY AND TEMPERATURE 0 LO = 0 dBSS - Unadjusted Sideband Suppression - dBc $P_{OUT} = -3 \text{ dBm}$ $V_{CC} = 5 V$ -10 -20 -30 85°C 25°C -40 -50 -60 500 1000 1500 2000 2500 3000 3500 4000 4500 0 f - Frequency - MHz

UNADJUSTED SIDEBAND SUPPRESSION

Figure 14.

UNADJUSTED SIDEBAND SUPPRESSION vs FREQUENCY AND SUPPLY VOLTAGE

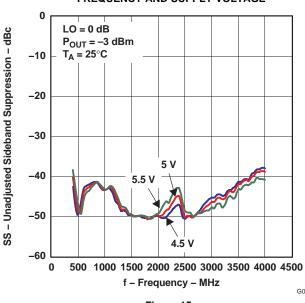


Figure 15.

UNADJUSTED SIDEBAND SUPPRESSION vs FREQUENCY AND LO POWER

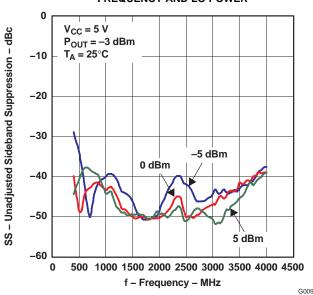


Figure 16.

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TYPICAL CHARACTERISTICS (continued)

ADJUSTED SIDEBAND SUPPRESSION

FREQUENCY AND TEMPERATURE

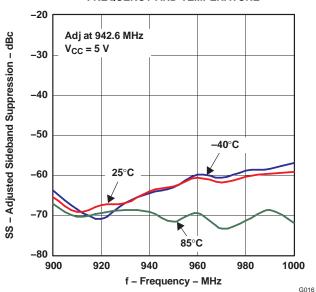


Figure 17.

ADJUSTED SIDEBAND SUPPRESSION vs

FREQUENCY AND TEMPERATURE

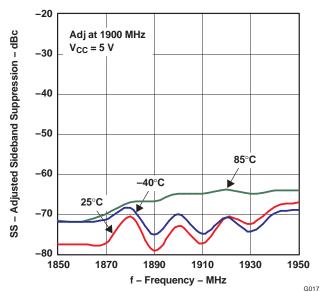


Figure 18.

ADJUSTED SIDEBAND SUPPRESSION

FREQUENCY AND TEMPERATURE

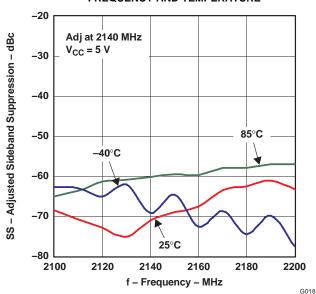


Figure 19.

NOISE AT 13-MHz OFFSET (dBm/Hz) vs

FREQUENCY AND SUPPLY VOLTAGE

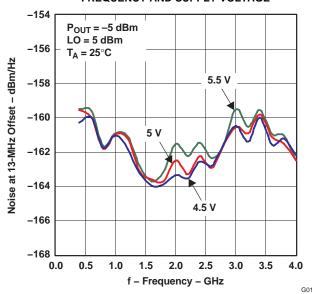


Figure 20.

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TYPICAL CHARACTERISTICS (continued)

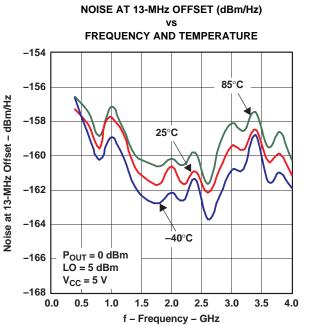


Figure 21.

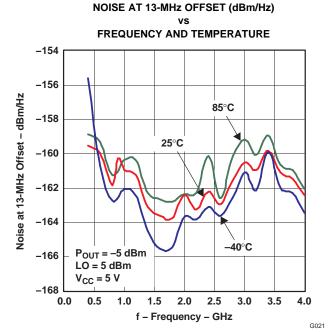


Figure 22.

NOISE AT 13-MHz OFFSET (dBm/Hz)

FREQUENCY AND TEMPERATURE

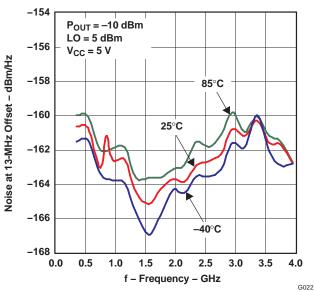


Figure 23.

UNADJUSTED CARRIER FEEDTHROUGH

FREQUENCY AND SUPPLY VOLTAGE

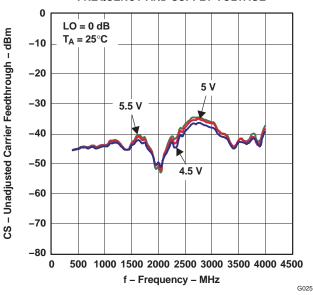


Figure 24.

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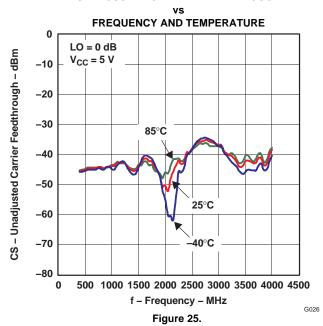


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TYPICAL CHARACTERISTICS (continued)

UNADJUSTED CARRIER FEEDTHROUGH





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APPLICATION INFORMATION AND EVALUATION BOARD

Basic Connections

- See Figure 26 for proper connection of the TRF3703315 and TRF370333 modulator.
- Connect a single power supply (4.5 V–5.5 V) to pins 18 and 24. These pins should be decoupled as shown on pins 4, 5, 6, and 7.
- Connect pins 2, 5, 8, 11, 12, 14, 17, 19, 20, and 23 to GND.
- Connect a single-ended LO source of desired frequency to LOP (amplitude between -5 dBm and 12 dBm).
 This should be ac-coupled through a 100-pF capacitor.
- Terminate the ac-coupled LON with 50 Ω to GND.
- Connect a baseband signal to pins 21 = I, $22 = \overline{I}$, 10 = Q, and $9 = \overline{Q}$.
- The differential baseband inputs should be set to the proper level, 3.3 V for the TRF370333 or 1.5 V for the TRF370315.
- RF_OUT, pin 16, can be fed to a spectrum analyzer set to the desired frequency, LO ± baseband signal. This pin should also be ac-coupled through a 100-pF capacitor.
- · All NC pins can be left floating.

ESD Sensitivity

RF devices may be extremely sensitive to electrostatic discharge (ESD). To prevent damage from ESD, devices should be stored and handled in a way that prevents the build-up of electrostatic voltages that exceed the rated level. Rated ESD levels should also not be exceeded while the device is installed on a printed circuit board (PCB). Follow these guidelines for optimal ESD protection:

- Low ESD performance is not uncommon in RF ICs; see the *Absolute Maximum Ratings* table. Therefore, customers' ESD precautions should be consistent with these ratings.
- The device should be robust once assembled onto the PCB unless external inputs (connectors, etc.) directly
 connect the device pins to off-board circuits.

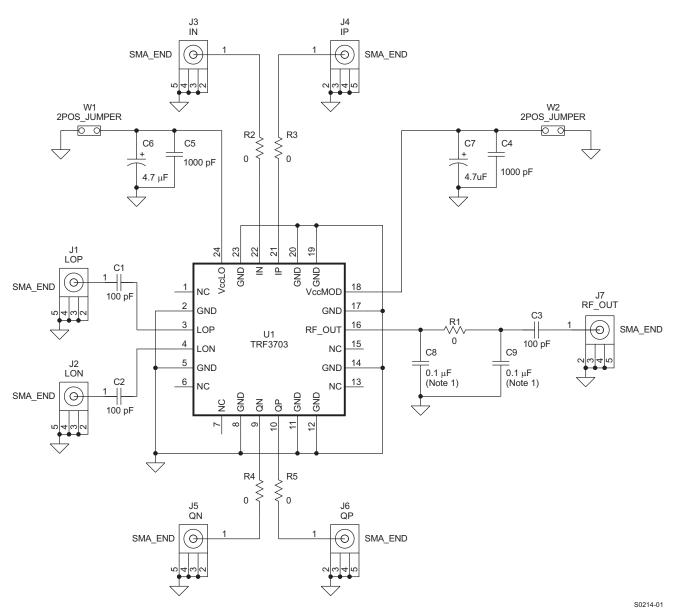
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(1) Do not install.

Figure 26. TRF3703 EVM Schematic

TEXAS

INSTRUMENTS

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Figure 27 shows the top view of the TRF3703 EVM board.

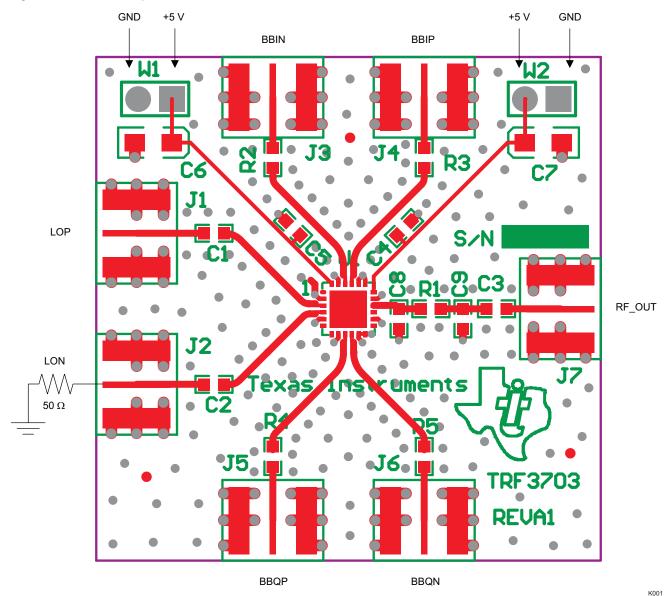


Figure 27. TRF3703 EVM Board Layout

Table 1. Bill of Materials for TRF3703 EVM

Value	Footprint	QTY	Part Number	Vendor	Digi-Key Number	REF DES	Not Installed
Tantalum 4.7-µF, 10-V, 10% capacitor	3216	2	T491A475K010AS	KEMET	399-1561-1-ND	C6, C7	
1000-pF, 50-V, 5% capacitor	603	2	ECJ-1VC1H102J	Panasonic	PCC2151CT-ND	C4, C5	
100-pF, 50-V, 5% capacitor	603	3	ECJ-1VC1H101J	Panasonic	PCC101ACVCT-ND	C1, C2, C3	
Capacitor	603	0					C8, C9
0-Ω resistor, 1/10-W, 5%	603	5	ERJ-3GEY0R00V	Panasonic	P0.0GCT-ND	R1, R2, R3, R4, R5	

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Table 1. Bill of Materials for TRF3703 EVM (continued)

Value	Footprint	QTY	Part Number	Vendor	Digi-Key Number	REF DES	Not Installed
TRF3703	24-QFN-PP- 4X4MM	1		TI		U1	
SMA connectors	SMA_END_ SMALL	6	16F3627	Newark	142-0711-821	J1, J2, J3, J4, J5, J6, J7	
2POS_HEADER	2POS_JUMP	2	HTSW-150-07-L-S	SAMTEC	N/A	W1, W2	

GSM Applications

The TRF370315 and TRF370333 are suited for GSM applications because of the high linearity and low noise level over the entire recommended operating range. These devices also have excellent EVM performance, which makes them ideal for the stringent GSM/EDGE applications.

WCDMA Applications

The TRF370315 and TRF370333 are also optimized for WCDMA applications where both adjacent-channel power ratio (ACPR) and noise density are critically important. Using Texas instruments' DAC568X series of high-performance digital-to-analog converters as depicted in Figure 28, excellent ACPR levels were measured with one-, two-, and four-WCDMA carriers. See Electrical Characteristics, fLO = 2140 MHz for exact ACPR values.

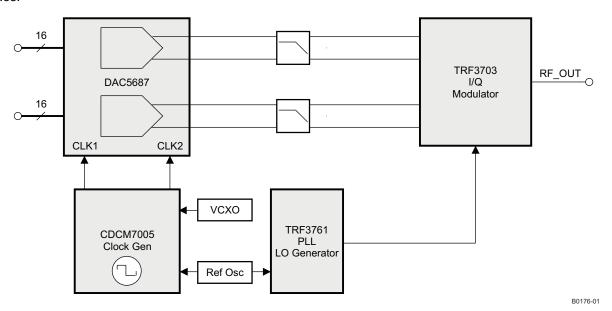


Figure 28. Typical Transmit Setup Block Diagram



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DEFINITION OF SPECIFICATIONS

Unadjusted Carrier Feedthrough

This specification measures the amount by which the local oscillator component is attenuated in the output spectrum of the modulator relative to the carrier. This further assumes that the baseband inputs delivered to the pins of the TRF370315 and TRF370333 are perfectly matched to have the same dc offset (VCM). This includes all four baseband inputs: I, \bar{I} , Q, and \bar{Q} . This is measured in dBm.

Adjusted (Optimized) Carrier Feedthrough

This differs from the unadjusted suppression number in that the baseband input dc offsets are iteratively adjusted around their theoretical value of VCM to yield the maximum suppression of the LO component in the output spectrum. This is measured in dBm.

Unadjusted Sideband Suppression

This specification measures the amount by which the unwanted sideband of the input signal is attenuated in the output of the modulator, relative to the wanted sideband. This further assumes that the baseband inputs delivered to the modulator input pins are perfectly matched in amplitude and are exactly 90° out of phase. This is measured in dBc.

Adjusted (Optimized) Sideband Suppression

This differs from the unadjusted sideband suppression in that the baseband inputs are iteratively adjusted around their theoretical values to maximize the amount of sideband suppression. This is measured in dBc.

Suppressions Overtemperature

This specification assumes that the user has gone though the optimization process for the suppression in question, and set the optimal settings for the I, Q inputs. This specification then measures the suppression when temperature conditions change after the initial calibration is done.

Figure 29 shows a simulated output and illustrates the respective definitions of various terms used in this data sheet. The graph assumes a baseband input of 50 kHz.

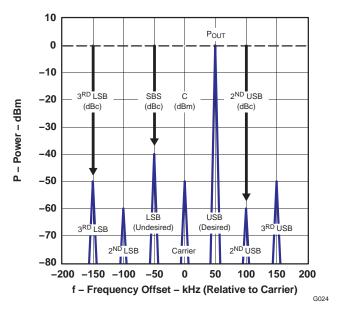


Figure 29. Graphical Illustration of Common Terms



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REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	nanges from Revision I (July, 2010) to Revision J	Page
	Changed <i>voltage gain</i> specifications for f _{LO} = 350-MHz performance data	4
•	Updated <i>voltage gain</i> specifications for f _{LO} = 400-MHz performance data	4
•	Revised <i>voltage gain</i> specifications for f _{LO} = 900-MHz performance data	5
•	Changed <i>voltage gain</i> specifications for f _{LO} = 1800-MHz performance data	
•	Revised <i>voltage gain</i> specifications for f _{LO} = 1960-MHz performance data	
•	Updated <i>voltage gain</i> specifications for f _{LO} = 2140-MHz performance data	
•	Revised <i>voltage gain</i> specifications for f _{LO} = 2500-MHz performance data	7
•	Changed <i>voltage gain</i> specifications for f _{LO} = 3600-MHz performance data	
•	Updated <i>voltage gain</i> specifications for f _{LO} = 4000-MHz performance data	
<u>.</u>	Replaced Figure 1	
CI	nanges from Revision H (January, 2010) to Revision I	Page
	Changed document title to reflect 0.35-GHz minimum operating level	1
•	Updated Description section to reflect 350-MHz minimum operation	
•	Changed LO frequency range minimum specification from 0.4 GHz to 0.35 GHz	4
•	Added <i>Electrical Characteristics</i> table for f _{LO} = 350-MHz performance data	4



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PACKAGE OPTION ADDENDUM

10-Jun-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
TRF370315IRGER	ACTIVE	VQFN	RGE	24	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TRF37 0315	Samples
TRF370315IRGET	ACTIVE	VQFN	RGE	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TRF37 0315	Samples
TRF370333IRGER	ACTIVE	VQFN	RGE	24	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TRF37 0333	Samples
TRF370333IRGET	ACTIVE	VQFN	RGE	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TRF37 0333	Samples
TRF370333IRGETG4	ACTIVE	VQFN	RGE	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	TRF37 0333	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available. **OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based filip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device

Addendum-Page 1



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PACKAGE OPTION ADDENDUM

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(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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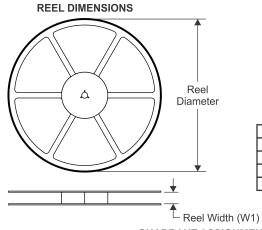
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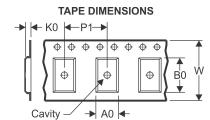


PACKAGE MATERIALS INFORMATION

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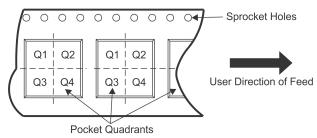
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

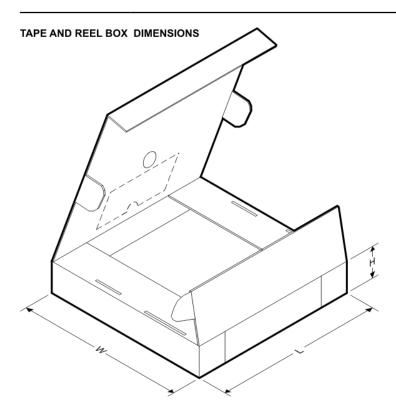
Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TRF370315IRGER	VQFN	RGE	24	3000	330.0	12.4	4.3	4.3	1.5	8.0	12.0	Q1
TRF370315IRGET	VQFN	RGE	24	250	180.0	12.4	4.3	4.3	1.5	8.0	12.0	Q1
TRF370333IRGER	VQFN	RGE	24	3000	330.0	12.4	4.3	4.3	1.5	8.0	12.0	Q2
TRF370333IRGET	VQFN	RGE	24	250	180.0	12.4	4.3	4.3	1.5	8.0	12.0	Q2

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PACKAGE MATERIALS INFORMATION

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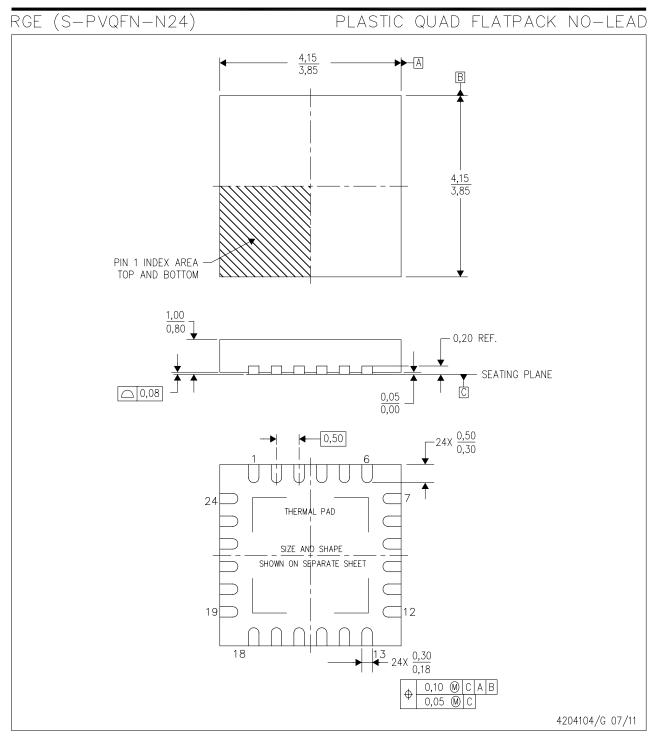


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TRF370315IRGER	VQFN	RGE	24	3000	338.1	338.1	20.6
TRF370315IRGET	VQFN	RGE	24	250	210.0	185.0	35.0
TRF370333IRGER	VQFN	RGE	24	3000	338.1	338.1	20.6
TRF370333IRGET	VQFN	RGE	24	250	210.0	185.0	35.0



MECHANICAL DATA



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Quad Flatpack, No-Leads (QFN) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F. Falls within JEDEC MO-220.





THERMAL PAD MECHANICAL DATA

RGE (S-PVQFN-N24)

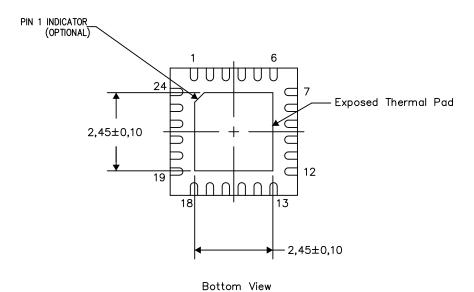
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Exposed Thermal Pad Dimensions

4206344-3/AK 08/15

NOTES: A. All linear dimensions are in millimeters

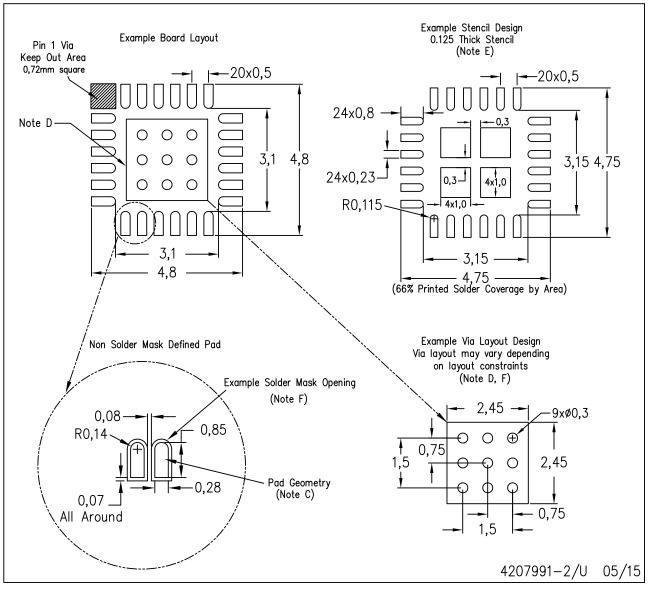




LAND PATTERN DATA

RGE (S-PVQFN-N24)

PLASTIC QUAD FLATPACK NO-LEAD



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.





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ıcts	Application

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